TOSHIBA Multi-Chip Device Silicon P Channel MOS Type (U-MOS III) / Schottky Barrier Diode

TPCF8B01

Notebook PC Applications Portable Equipment Applications

- Low drain-source ON resistance: R_{DS} (ON) = 72 mΩ (typ.)
- High forward transfer admittance: |Yfs| = 4.7 S (typ.)
- Low leakage current: I_{DSS} =-10 μA (max) (V_{DS} = -20 V)
- Enhancement-model: V_{th} = -0.5 to-1.2 V (V_{DS} =-10 V, I_{D} = -200 μ A)
- Low forward voltage: V_{FM(2)} = 0.46 V (typ.)

Absolute Maximum Ratings

MOSFET (Ta = 25°C)

COC	haracteristics	Symbol	Rating	Unit
Drain-source voltage		V _{DSS}	-20	V
Drain-gate voltag	ge (R _{GS} = 20 kΩ)	V _{DGR}	-20	V
Gate-source volt	age	V _{GSS}	±8	V
1007.0	DC (Note 1)	I _D 100	-2.7	1
Drain current	Pulse (Note 1)	I _{DP}	-10.8	TA
Single pulse ava	lanche energy (Note 4)	E _{AS}	1.2	mJ
Avalanche curre	nt CO	I _{AR}	-1.35	Α
Repetitive avalanche energy Single-device value at dual operation (Note 2a, 3b, 5)		E _{AR}	0.11	mJ

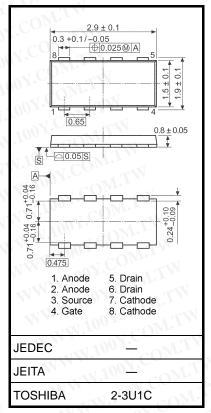
SBD (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Repetitive peak reverse voltage	V _{RRM}	20	V.V.
Average forward current (Note 2a, 6)	I _{F(AV)}	1.0	ACC
Peak one cycle surge forward current (non-repetitive)	I _{FSM}	7(50Hz)	A ₁ .C

Absolute Maximum Ratings for MOSFET and SBD (Ta = 25°C)

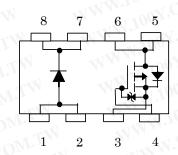
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Characteristics		Symbol	Rating	Unit
Drain power dissipation	Single-device operation (Note 3a)	P _{D (1)}	1.35	111.100
(t = 5 s) (Note 2a)	Single-device value at dual operation (Note 3b)	P _{D (2)}	1.12	W
Drain power	Single-device operation (Note 3a)	P _{D (1)}	0.53	V VV
dissipation (t = 5 s) (Note 2b)	Single-device value at dual operation (Note 3b)	P _{D (2)}	0.33	
Channel temperature		T_ch	150	°C
Storage temperature range		T _{stg}	-55~150	°C

Unit: mm



Weight: 0.011 g (typ.)

Circuit Configuration



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Note: For (Note 1), (Note 2), (Note 3), (Note 4), (Note 5) and (Note 6), please refer to the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics for MOSFET and SBD

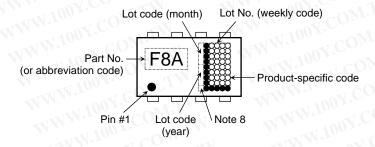
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	Charac	cteristics	Symbol	Max	Unit
	Thermal resistance, channel to ambient	Single-device operation (Note 3a)	R _{th} (ch-a) (1)	92.6	°C/W
)	(t = 5 s) (Note 2a)	Single-device value at dual operation (Note 3b)	R _{th (ch-a) (2)}	111.6	NVV.
	Thermal resistance,	Single-device operation (Note 3a)	R _{th (ch-a) (1)}	235.8	°C/W
	channel to ambient $(t = 5 s)$ (Note 2b)	Single-device value at dual operation (Note 3b)	R _{th (ch-a) (2)}	378.8	30/00

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This transistor is an electrostatic sensitive device. Please handle with caution.

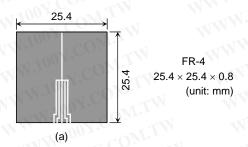
Schottky barrier diodes are having large-reverse-current-leakage characteristic compare to the other rectifier products. This current leakage and improper operating temperature or voltage may cause thermal runaway. Please take forward and reverse loss into consideration when you design.

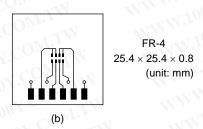
Marking (Note 7)



Note 1: Please use devices on condition that the channel temperature is below 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a) (b) Device mounted on a glass-epoxy board (b)





Note 3: a) The power dissipation and thermal resistance values are shown for a single device (During single-device operation, power is only applied to one device.). b) he power dissipation and thermal resistance values are shown for a single device

(During dual operation, power is evenly applied to both devices.).

Note 4: V_{DD} =-16 V, T_{ch} = 25°C (initial), L = 0.5 mH, R_G = 25 Ω , I_{AR} = -1.35 A

Note 5: Repetitive rating; Pulse width limited by maximum channel temperature.

Note 6: Rectangular waveform ($\alpha = 180^{\circ}$), $V_R = 15V$.

Note 7: Black round marking "•" locates on the left lower side of parts number marking "F8A" indicates terminal No. 1.

Note 8 A dot marking identifies the indication of product Labels. Without a dot: [[Pb]]/INCLUDES > MCV With a dot: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Electrical Characteristics (Ta = 25°C)

MOSFET

Ch	aracteristics	Symbol	Test Condition	Min	Тур.	Max	U
Gate leakage cui	rrent	I _{GSS}	$V_{GS} = \pm 8 \text{ V}, V_{DS} = 0 \text{ V}$	$\Gamma T_{d_{\mu}}$	_	±10	μ
Drain cut-off curr	ent	I _{DSS}	V _{DS} = -20 V, V _{GS} = 0 V	1ªV	_	-10	μ
Drain aguras bro	Drain-source breakdown voltage		I _D = -10 mA, V _{GS} = 0 V	-20	N —	_	V
Drain-source bre	akdown voltage	V (BR) DSX	I _D = -10 mA, V _{GS} = 8V	-12	W-	_	1
Gate threshold v	oltage	V _{th}	$V_{DS} = -10 \text{ V}, I_{D} = -200 \mu\text{A}$	-0.5		-1.2	١
OMITWO	W.	R _{DS} (ON)	V _{GS} = -1.8 V, I _D = -0.7 A	c o M	215	300	
Drain-source ON	resistance	R _{DS} (ON)	$V_{GS} = -2.5 \text{ V}, I_D = -1.4 \text{A}$	71	110	160	m
I.COM		R _{DS} (ON)	V _{GS} = -4.5 V, I _D = -1.4 A		72	110	
Forward transfer	admittance	Y _{fs}	V _{DS} = -10 V, I _D = -1.4 A	2.4	4.7	W —	(
Input capacitance	9	C _{iss}	M. W.	N Y. C	470	W	
Reverse transfer	capacitance	C _{rss}	V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz	5 7 (70		pF
Output capacitan	ce	C _{oss}	OM.TW	100.	80		
100X.CO1	Rise time	t _r	V _{GS} 0 V	UVGS II a alv	50		N
Switching time	Turn-on time	t _{on}		<u> </u>	9	$\Gamma.\overline{N}_{\Omega}$	- vn
N.W.	Fall time	t _f . 10	7.4 W W.7.5	N 4 1.1	8	COM.	
	Turn-off time	t _{off}	$V_{DD} \simeq -10 \text{ V}$ Duty \leq 1%, $t_W = 10 \mu\text{s}$	MM	26	CO_N	1.7
Total gate charge (gate-source plus		Qg	V _{DD} ≃ -16 V, V _{GS} = -5 V,	MM.	600	V.C.	M
Gate-source cha	rge	Q _{gs}	$I_D = -2.7 \text{ A}$		4	30 <u></u> C	n
Gate-drain ("mille	er") charge	Q _{gd}	1100Y.CO.T.TY	7//	2	001.	

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Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Drain reverse current Pulse (Note 1)	I _{DRP}	W.Ino COM.	_		-10.8	Α
Forward voltage (diode)	V _{DSF}	I _{DR =} -2.7 A, V _{GS} = 0 V			-1.2	V

SBD

Forward voltage (diode)	V _{DSF}	$I_{DR} = -2.7 \text{ A}, V_{GS} = 0 \text{ V}$		_	-1.2	V
BD WWW.100X.C						
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Deal Consent of the WWW.100	V _{FM(1)}	I _{FM} = 0.7 A		0.43	41	V
Peak forward voltage	V _{FM(2)}	I _{FM} = 1.0 A	1 T	0.46	0.49	V
Repetitive peak reverse current	I _{RRM}	V _{RRM} = 20 V	Ohr.	TV.	50	μА
Junction capacitance	Cj	V _R = 10 V, f = 1 MHz	CO_{N_T}	54	_	pF

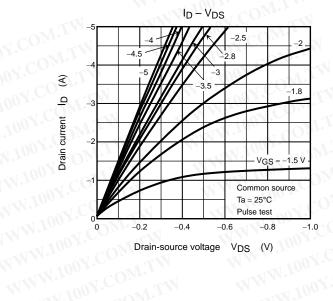
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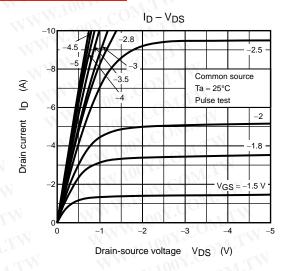
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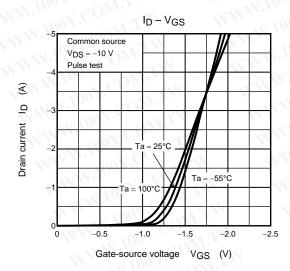
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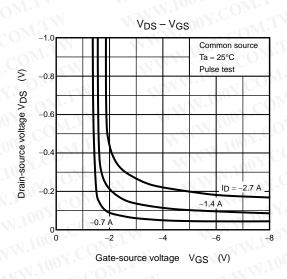
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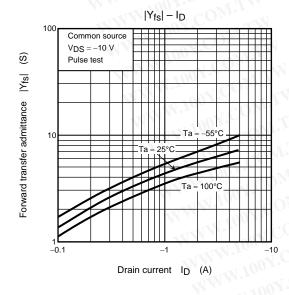
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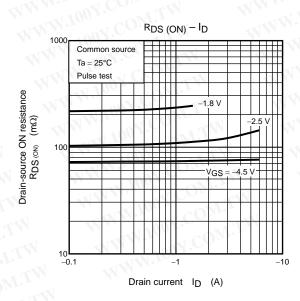








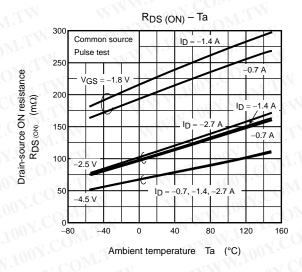


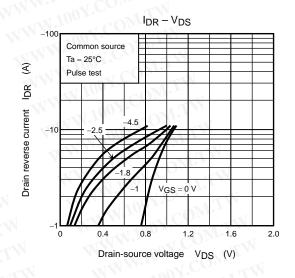


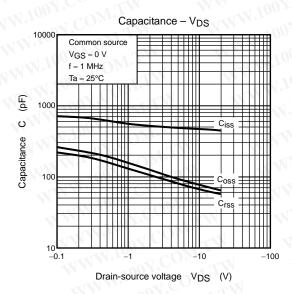
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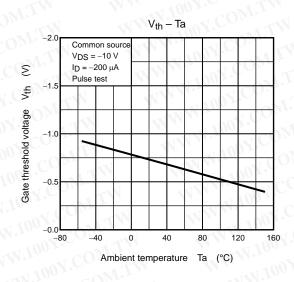
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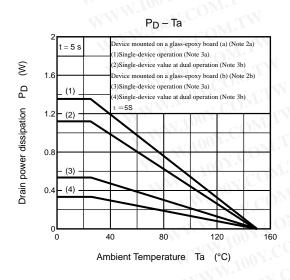
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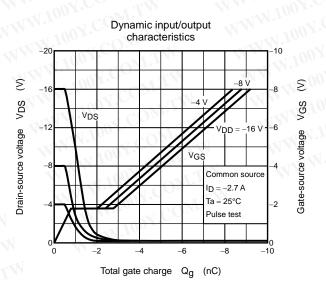


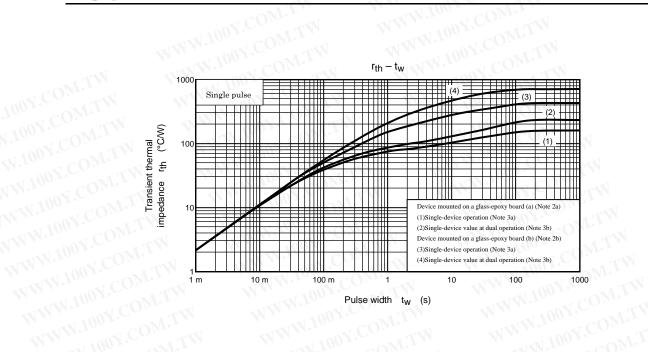




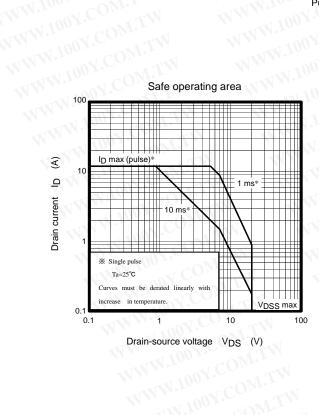








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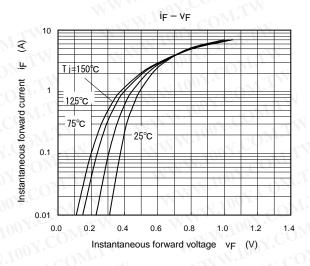


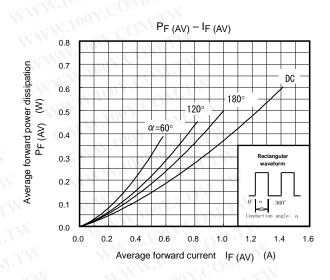
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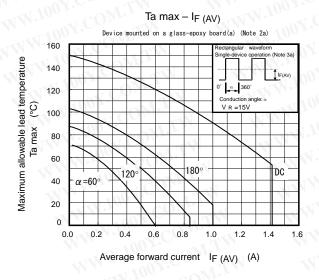
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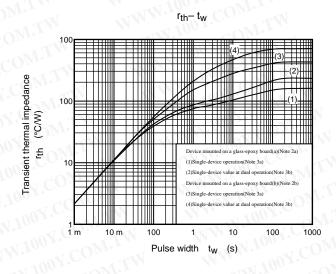
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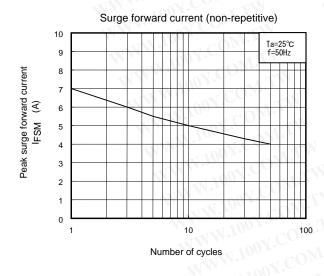
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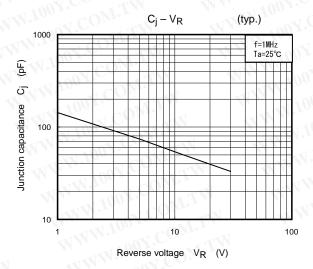




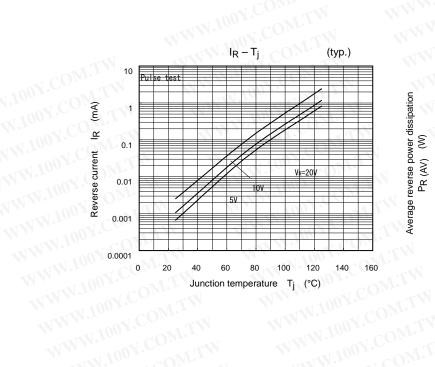


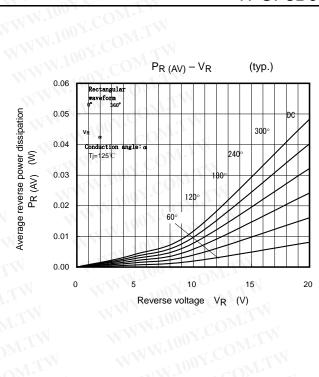






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9